Reliability Qualification Report for 256Mb DDR SDRAM with Pb/Halogen Free (Industrial and Extended Test)



Reliability Qualification Report: 16M×16, 6Xnm SDRAM

Part #s: NDD36PFD-2AET, NDD36PFD-2AIT, NDD36PT6-2AET, NDD36PT6-2AIT

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RELIABILITY TEST SUMMARY

Test Item	Test Condition	Pass Criteria	Test Result
EFR	1.2*Vint, 125°C, 12Hrs	0 - 1 (Year) ≦1000 (DPM)	0/1000 0 DPM (PASS)
OLT		1 - 10 (Year)	0/231 22 FIT (PASS)
OLI	1.1*Vint, 125°C, 1000Hrs	≦50 (FIT)	MTBF= 45 x 10 ⁶ Hrs
MSLT	Level III	0/1 (A/R)	0/304 (PASS)
HTST	150°C, 1000Hrs	0/1 (A/R)	0/76 (PASS)
TCT	-65°C~ +150°C, @3cph, 500Cycles	0/1 (A/R)	0/76 (PASS)
PCT	121°C, 100%R.H., 2.0atm, 168Hrs for TSOP, 96Hrs for BGA	0/1 (A/R)	0/76 (PASS)
HAST	130°C, 85%R.H., 2.3atm, 1.95V, 96Hrs	0/1 (A/R)	0/76 (PASS)
TH	85°C, 85%R.H., 1000Hrs	0/1 (A/R)	0/76 (PASS)
	HBM: R=1.5K Ω , C=100pF	≧±2KV	0/3 (PASS)
ESD	MM: R=0KΩ, C=200pF	≧±200V	0/3 (PASS)
	CDM: Non-Socket Mode	≧±1KV	0/3 (PASS)
Vtr (+) ≥1.5 * Vcc Vtr (-) ≤-0.5 * Vcc Itr(+)≥100mA Itr(-)≤-100mA			0/6 (PASS)

Moisture Sensitivity Level Test Flow & Condition:

Electrical Test → SAT → TC (-65°C~+150°C, 5Cycles) → Bake (125°C, 24Hrs) → Soak Level III (30°C, 60%R.H., 192Hrs) → Convection Reflow (260 +5/-0°C, 0~20Secs, 3Cycles) → Electrical Test → SAT



INTRODUCTION

In order to meet the most stringent market demands for high quality and reliable semiconductor components, Insignis maintains a strict reliability program for all its products.

The purpose of this report is to give an overview of the reliability status of NDD36P. Accelerated tests are performed on the product, and then the results are extrapolated to standard operating conditions in order to calculate and estimate the component's failure rate.

PRODUCT INFORMATION

The NDD36P is a 16Mx16 bit high-speed CMOS Double Data Rate Synchronous Dynamic Random Access Memory (DDR SDRAM) operating from a single 1.7 to 1.95 volt power supply.

By employing new CMOS circuit design technologies and advanced DRAM process technologies, the NDD36P is well suited for applications requiring high memory bandwidth and is particularly well suited to high performance applications. The NDD36P is packaged in a standard 66-pin, plastic 400mil TSOPII or a standard 60-ball, plastic 8x13mm FBGA.

RELIABILITY

Many stress tests have been standardized in such documents as MIL-STD- 883, EIAJ-IC-121, EIA/JESD22 and JEDEC-NOTE-17. From these standards, Insignis has selected a series of tests to ensure that reliability targets are being met. These tests, including the life test, environmental test, ESD test and latch-up test, are discussed in the following sections.

Sample Preparation Flow

CP Assembly 66L TSOP or 60B BGA FT Sampling Good Parts for Reliability Test



Life Test

The purpose of the Early Failure Rate (EFR) is to estimate the infant mortality failure rate that occurs within the first year of normal device operation by accelerating infant mortality failure mechanisms. The oven temperature for the EFR test is 125°C. Testing is performed with dynamic signals applied to the device, and the voltage is 1.2*Vint.

The purpose of the Operating Life Test (OLT) is to determine the reliability of products by accelerating thermally activated failure mechanisms by subjecting samples to extreme temperatures under biased operating condition of 1.1*Vint. The test is used to predict long-term failure rates in terms of FITs (failures in time), with one FIT representing one failure in 10° device-hours. The test samples are screened directly after final electrical testing. The oven temperature for the OLT is 125°C. Testing is performed with dynamic signals applied to the device, and the voltage is 1.1*Vint.

Test Flow

EFR Test Flow

B/I 12Hrs (125°C, 1.2*Vint) → Electrical Test (85°C, 25°C, -40°C)

OLT Test Flow

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B/I 168Hrs (125°C, 1.1*Vint) - Electrical Test (85°C, 25°C, -40°C)

B/I 500Hrs (125°C, 1.1*Vint) - Electrical Test (85°C, 25°C, -40°C)

B/I 1000Hrs (125°C, 1.1*Vint) - Electrical Test (85°C, 25°C, -40°C)
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Test Criteria

Test Item	Reference Standard	Test Condition	Prediction Duration	Pass Criteria
EFR 12Hrs	IECD33 A100	Vcc= 1.2*Vint Ta= 125°C	0 – 1 (Year)	≦1000 (DPM)
OLT 1000Hrs	JESD22-A108	Vcc= 1.1*Vint Ta= 125°C	1 – 10 (Year)	≦50 (FIT)



Failure Rate Calculation and Test Result

The life test is performed for the purpose of accelerating the probable electrical and physical weakness of devices subjected to the specified conditions over an extended time period.

By choosing the appropriate thermal activation energy (Ea), data taken at an elevated temperature can be translated to a lower standard operating temperature through the Arrhenius equation:

T(AF) = Exp [(Ea/k)*(1/Tn-1/Ts)]...(1)

where

T(AF)= Temperature Acceleration Factor

Tn= Normal Temperature in Absolute Temperature (K)

Ts= Stress Temperature in Absolute Temperature (K)

k= Boltzmann's Constant (8.62*10^-5 eV/K)

Ea= Thermal Activation Energy

By choosing the appropriate electrical field acceleration rate constant (Vf), data taken at an elevated voltage can be translated to a lower standard operating voltage through the Eyring model:

E(AF) = Exp [Vf*(Vs-Vn)]...(2)

where

E(AF)= Electrical Field Acceleration Factor

Vn= Normal Operating Voltage

Vs= Stress Operating Voltage

Vf= Electrical Field Acceleration Rate Constant

By combining the equation (1) & (2), the failure rate (λ) can be calculated by using the following equation:

$\lambda(FIT) = [(Lamda of 60\% CL) / (2*TDH*AF)]*10^9...(3)$

where

λ= Failure Rate in FIT

AF= Acceleration Factor

= T(AF) * E(AF)

TDH= Total Device-Hours of the Test

= Device No. * Hour

Lamda of CL= 60% Confidence Level (Refer to the Following Table)



DF	Lamda
1	0.70
2	1.83
3	2.95
4	4.04
5	5.13
6	6.21
7	7.28
8	8.35
9	9.41
10	10.50

DF= 2 * (Failure No. + 1)

Therefore, from equation (3), we can get the FIT number for our OLT experiment. The MTBF can be also calculated from the reciprocal of the FIT rate multiplied by 10⁹.

EFR Test Result

A summary of Early Failure Rate (EFR) data for the NDD36P is listed in Table 1, where the total of 1,000 devices at 125°C has been collected with 0 failures.

 Test Item
 Sample
 Test Result (Failure / Sample Size)
 Failure Mode

 12 Hrs
 1000ea
 0/1000 [= 0 DPM]
 N/A

Table 1. EFR Test Result for 0-1 Year Prediction

OLT Test Result

A summary of Operating Life Test (OLT) data for the NDD36P is listed in Table 2, where the total of 231,000 device-hours at 125°C has been collected with 0 failures. We then use Ea= 0.5eV and Vf= 7.0(1/V) (a worse case value from the foundry) to calculate the failure rate with a 60% confidence level. Table 3 shows the final result that the failure rate of 22 FIT at Ta = 55°C and Vcc = 1.8V is predicted.



Table 2. OLT Test Result

Test Item	Sample	Test Result (Failure / Sample Size)			Failure Mode	
restitein	Sample	168 Hrs	500 Hrs	1000 Hrs	ranure widue	
OLT	231ea	0/231	0/231	0/231	N/A	

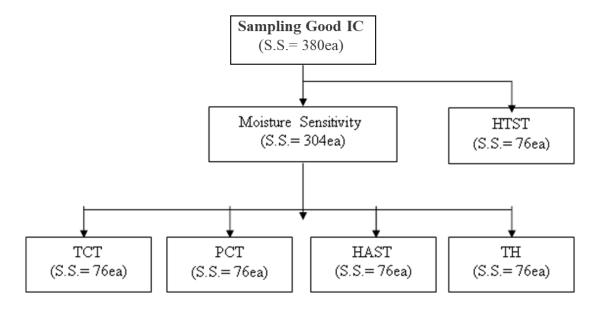
Table 3. OLT for 1-10 Year Failure Rate Prediction

Sample	Device-	Total	Failure Rate Prediction (Ea= 0.5eV, Vf= 7.0(1/V))		
Sample	Hours	Failures	55°C & 1.8V (% / 1000hrs)	λ (FIT)	MTBF (Hr)
231ea	231,000	0ea	0.0022	22	45 x 10 ⁶

Environmental Test

The purpose of environmental testing is to evaluate the ability of the semiconductor device to withstand temperature stress, humidity stress, electrical stress or any combination of these. It can reveal not only package quality issues but also possible errors in wafer process or chip design interacting with the assembly process.

Test Flow



Test Condition and Time

Moisture Sensitivity Test

The purpose of the moisture sensitivity test is to identify the classification level of nonhermetic solid state Surface Mount Devices (SMDs) that are sensitive to moisture-induced stress so that they can be properly packaged, stored, and handled to avoid subsequent thermal and mechanical damage during the assembly solder reflow attachment and/or repair operation.

*Moisture Sensitivity Test Flow

Electrical Test SAT TC (-65°C~+150°C, 5Cycles) Bake (125°C, 24Hrs) Soak Level III (30°C, 60%R.H., 192Hrs) Convection Reflow (260 +5/-0°C, 0~20Secs, 3Cycles) Electrical Test SAT

Test Item	Test Condition (Level III)	Test Time
Temp. Cycle	-65°C~ +150°C	5Cycles
Bake	125°C	24Hrs
Unbiased Temp- Humidity Soak	30°C, 60%R.H.	192Hrs
Convection Reflow	a) Preheat Temp. = 60~120 seconds Max. b) Temp. maintained above 217°C = 60~150 seconds c) Temp. maintained above 230°C = 30~60 seconds d) Temp. maintained above 255°C = 20~40 seconds e) Peak Temp. Range = 260(-0/+5)°C & Max. 20 seconds P.S. Time 25°C to Peak Temp. = 8 minutes Max.	3Cycles



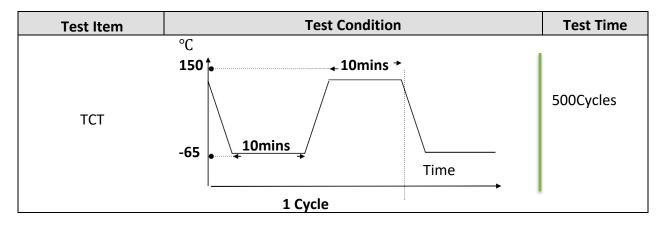
High-Temperature Storage Life Test

The high-temperature storage life test measures device resistance to a high-temperature environment that simulates a storage environment. The stress temperature is set to 150°C in order to accelerate the effect of temperature on the test samples. In the test, no voltage bias is applied to the devices.

Test Item	Test Condition	Test Time
HTST	150°C	1000Hrs

Temperature Cycling Test

The purpose of the temperature cycling test is to study the effect of thermal expansion mismatch among the different components within a specific die and package system. The cycling test system has a cold dwell at -65°C and a hot dwell at 150°C, and it employs a circulating air environment to ensure rapid stabilization at a specified temperature. During the temperature cycling test, devices are inserted into the cycling test system and held at cold dwell for 10 minutes, then the devices are heated to hot dwell for 10 minutes. One cycle includes the duration at both extreme temperatures and the two transition times. The transition period is less than one minute at 25°C. Samples of surface mount devices must first undergo preconditioning and pass a final electrical test prior to the temperature cycling test.



Pressure Cooker Test

The pressure cooker test is an environmental test that measures device resistance to moisture penetration and the effect of galvanic corrosion. The stress conditions for the pressure cooker are 121°C, 100% relativity humidity, and 2.0atm pressure. Samples of surface mount devices are subjected to preconditioning and a final electrical test prior to the pressure cooker test.

Test Item Test Condition		Test Time
PCT	121°C, 100%R.H., 2.0atm	168Hrs for TSOP, 96Hrs for BGA



Highly-Accelerated Temperature and Humidity Stress Test

The highly-accelerated temperature and humidity stress test is performed for the purpose of evaluating the reliability of nonhermetic packaged solid-state devices in an environment with high humidity. It employs severe conditions of temperature, humidity, and bias that accelerate the penetration of moisture through the external protective material (encapsulant or seal) or along the interface between the external protective material and the metallic conductor that pass through it. The stress conditions of the HAST are 130°C, 85% relativity humidity, 2.3atm pressure, and 1.95V maximum operating voltage. Samples of surface mount devices are subjected to preconditioning and a final electrical test prior to the highly-accelerated temperature and humidity stress test.

Test Item	Test Item Test Condition Te	
HAST	130°C, 85%R.H., 2.3atm, 1.95V	96Hrs

Steady State Temperature and Humidity Life Test

The temperature and humidity test is an environmental test designed to measure the corrosion and moisture resistance of plastic-encapsulated circuits. The stress conditions of the TH are 85°C and 85% relativity humidity. Samples of surface mount devices are subjected to preconditioning and a final electrical test prior to the steady state temperature and humidity life test.

Test Item	Test Condition	Test Time
TH	85°C, 85%R.H.	1000Hrs



Test Criteria and Result

Table 4 shows the test results and reference standard of the environmental test. The test status and results of NDD36P is also presented in the table. The status of PASS in all of these test results means that Insignis' SDRAM products are much more endurable in most service environments.

Test Item	Reference Standard	A/R Criteria	Failure/S.S.	Status	Failure Mode
Moisture Sensitivity	J-STD-020	0/1	0/304	PASS	N/A
HTST	JESD22-A103	0/1	0/76	PASS	N/A
TCT*	JESD22- A104	0/1	0/76	PASS	N/A
PCT*	JESD22- A102	0/1	0/76	PASS	N/A
HAST*	JESD22-A110	0/1	0/76	PASS	N/A
TH*	JESD22- A101	0/1	0/76	PASS	N/A

Table 4. Environmental Test Criteria and Result

ESD Test

Electrical discharge into a semiconductor product is one of the leading causes of device failure in the customer's manufacturing process. Insignis performs the ESD test to ensure that the performance of NDD36P will not be degraded to an unacceptable level by exposure to a succession of electrostatic discharge. The test methods and test results are shown in Table 5.

Test Method Result **Test Item** (F/S.S) Reference Standard **Test Condition** Criteria Sample H.B.M. JESD22-A114 0/3 R=1.5K Ω , C=100pF ≥±2KV 3ea M.M. JESD22-A115 R=0K Ω , C=200pF ≥±200V 3ea 0/3 C.D.M. JESD22-C101 Non-Socket Mode 3ea 0/3 ≥±1KV

Table 5. ESD Test Condition and Result

^{*} Sampling from Moisture Sensitivity

Latch-Up Test

CMOS products can be prone to over-voltage exceeding the maximum device rating if the parasitic p-n-p-n SCRs (Silicon-controlled rectifier) are improperly biased. When the SCR turns on, it draws excessive current and causes products to be damaged by thermal runaway. The Table 6 shows the latch-up test method and the test result of no failures.

Table 6. Latch-Up Test Condition and Result

Test Item	Test Method			Result
	Reference Standard	Test Condition & Criteria	Sample	(F/S.S)
Latch-Up	JESD78	Vtr (+) ≧1.5 * Vcc Vtr (-) ≦-0.5 * Vcc Itr(+)≧100mA	6ea	0/6
		Itr(-)≦-100mA		

CONCLUSION

Reliability testing is done to ensure the ability of a product to perform a required function under specific conditions for a certain period of time. Through these tests, the devices with potential failures can be screened out before shipping to the customer. At the same time, the test results are fed back into our process, design and other related departments for improving product quality and reliability.

According to the lifetime test data, the short-term 12Hrs failure rate (= normal operation of 0-1 year) of NDD36P is equal to 0 DPM at Ta=55°C and Vcc=1.8V with 60% confidence level AND the long-term 1000Hrs failure rate (= normal operation of 1-10 years) of NDD36P is equal to 22 FIT at Ta=55°C and Vcc=1.8V with 60% confidence level. The results of the environmental test, ESD test and latch-up test also ensure that NDD36P is manufactured under a precise control of quality work by Insignis and its subcontractors. **Thus, based on industry-defined reliability test standards, this Insignis product passes all of the above tests**.

With the extensive research and development activities and the cooperation of all departments, Insignis continuously sets and maintains a higher standard of quality and reliability to satisfy the future demand of its customers.

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